

Mayeul d'Avezac

List of Publications by Year in descending order

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Version: 2024-02-01

14

papers

776

citations

759233

12

h-index

1058476

14

g-index

14

all docs

14

docs citations

14

times ranked

1394

citing authors

#	ARTICLE	IF	CITATIONS
1	Abnormal morphology biases hematocrit distribution in tumor vasculature and contributes to heterogeneity in tissue oxygenation. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2020, 117, 27811-27819.	7.1	40
2	A Caching Scheme To Accelerate Kinetic Monte Carlo Simulations of Catalytic Reactions. <i>Journal of Physical Chemistry A</i> , 2020, 124, 7140-7154.	2.5	8
3	Robust sparse image reconstruction of radio interferometric observations with purify. <i>Monthly Notices of the Royal Astronomical Society</i> , 2018, 473, 1038-1058.	4.4	39
4	The atomistic structure of yttria stabilised zirconia at 6.7 mol%: an ab initio study. <i>Physical Chemistry Chemical Physics</i> , 2016, 18, 31277-31285.	2.8	15
5	Chemical Descriptors of Yttria-Stabilized Zirconia at Low Defect Concentration: An <i>< i>ab Initio</i></i> Study. <i>Journal of Physical Chemistry A</i> , 2015, 119, 6412-6420.	2.5	16
6	Li-doped Cr ₂ MnO ₄ : A New p-type Transparent Conducting Oxide by Computational Materials Design. <i>Advanced Functional Materials</i> , 2013, 23, 5267-5276.	14.9	57
7	Parallel kinetic Monte Carlo simulation framework incorporating accurate models of adsorbate lateral interactions. <i>Journal of Chemical Physics</i> , 2013, 139, 224706.	3.0	122
8	Genetic-Algorithm Discovery of a Direct-Gap and Optically Allowed Superstructure from Indirect-Gap Si and Ge Semiconductors. <i>Physical Review Letters</i> , 2012, 108, 027401.	7.8	103
9	Genomic Design of Strong Direct-Gap Optical Transition in Si/Ge Core/Multishell Nanowires. <i>Nano Letters</i> , 2012, 12, 984-991.	9.1	54
10	Learning to Predict Physical Properties using Sums of Separable Functions. <i>SIAM Journal of Scientific Computing</i> , 2011, 33, 3381-3401.	2.8	10
11	Universal Electrostatic Origin of Cation Ordering in A ₂ BO ₄ Spinel Oxides. <i>Journal of the American Chemical Society</i> , 2011, 133, 11649-11654.	13.7	71
12	Doping Rules and Doping Prototypes in A ₂ BO ₄ Spinel Oxides. <i>Advanced Functional Materials</i> , 2011, 21, 4493-4501.	14.9	176
13	Simple Point-Ion Electrostatic Model Explains the Cation Distribution in Spinel Oxides. <i>Physical Review Letters</i> , 2010, 105, 075501.	7.8	48
14	Finding the atomic configuration with a required physical property in multi-atom structures. <i>Journal of Physics Condensed Matter</i> , 2007, 19, 402201.	1.8	17